

isc N-Channel MOSFET Transistor

RD3P175SN

FEATURES

- Drain Current –I_D= 17.5A@ T_C=25 $^\circ\!\!\mathbb{C}$
- Drain Source Voltage-: V_{DSS}= 100V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 105m Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

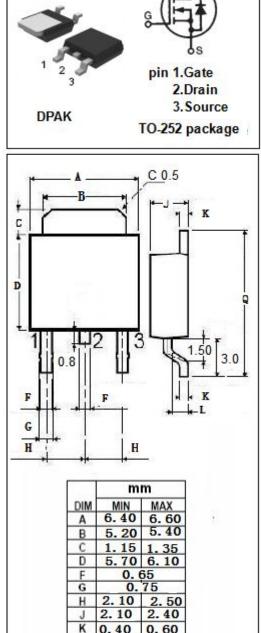
ADSOLUTE WAATINUW RATINGS(Ta-25 C)						
SYMBOL	PARAMETER VAL		UNIT			
V _{DSS}	Drain-Source Voltage	100	V			
V _{GS}	Gate-Source Voltage-Continuous	Source Voltage-Continuous ±20				
ID	Drain Current-Continuous	17.5	A			
I _{DM}	Drain Current-Single Pluse	35	A			
P _D	Total Dissipation @T _c =25℃ 20		W			
TJ	Max. Operating Junction Temperature	150	°C			
T _{stg}	Storage Temperature	-55~150	°C			

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL

Rth j-c



isc website: <u>www.iscsemi.com</u>

PARAMETER

Thermal Resistance, Junction to Case

MAX

6.25

UNIT

°C/W

0

0.90

9.90



isc N-Channel MOSFET Transistor

RD3P175SN

ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V(BR)DSS	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	100		V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 1mA	1	2.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 8.8A		105	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0		±10	uA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 100V; V _{GS} = 0		1	μA
V _{SD}	Forward On-Voltage	I _S = 17.5A; V _{GS} = 0		1.5	V

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.